Product Document

Datasheet

DS001033

NanEyeM

Miniature Camera Module

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Content Guide

1 General Description

NanEyeM is a miniature sized image sensor for vision applications where size is a critical factor. The ability of the camera head to drive a signal through long cables makes this the ideal component for minimal diameter endoscopes.

With a footprint of a just 1 mm^2, it features a 320x320 resolution with a high sensitive 2.4-micron rolling shutter pixel, with large full well capacitance. The sensor has been specially designed for medical endoscopic applications where high SNR is mandatory. The sensor has a high frame rate of about 50 fps to permit SNR enhancement and a smooth, low delay display over a wide range of standard interfaces. On the other side the frame rate can be set as low as 9 fps for usage of extended exposure time and lower power consumption.

The sensor includes a 10-bit ADC and a bit serial LVDS data interface. The sensor is able to drive the signal through a cable length of up to 3 m.

The data line is semi duplex, such that configuration can be communicated to the sensor in the frame brake. The exposure time, dark level, analog gain and frame rate can be programmed over the serial configuration interface.

1.1 Key Benefits & Features

The benefits and features of NanEyeM, Miniature Camera Module are listed below:

Figure 1:
Added Value of Using NanEyeM

| Benefits	Features
Designed for the toughest confined space requirements	Footprint of 1 mm^2 with cable assembly
Smooth and accurate image	Frame rate of 4 – 49 fps @ 320x320 resolution
Reach further	Possible to drive a signal through an endoscope of up to 3 m
Flexible connection	Possible to switch the serial interface to single ended mode for easier connection to ISPs.
Affordable single use application	Designed with a focus on cost efficiency
Envision the unseen	2.4-micron high sensitive pixel with 102.4 k pixel resolution

1.2 Applications

- Medical Applications
  - Endoscopy
  - Intraoral Scanning

1.3 Block Diagram

The functional blocks of this device are shown below:

Figure 2:
Functional Blocks of NanEyeM
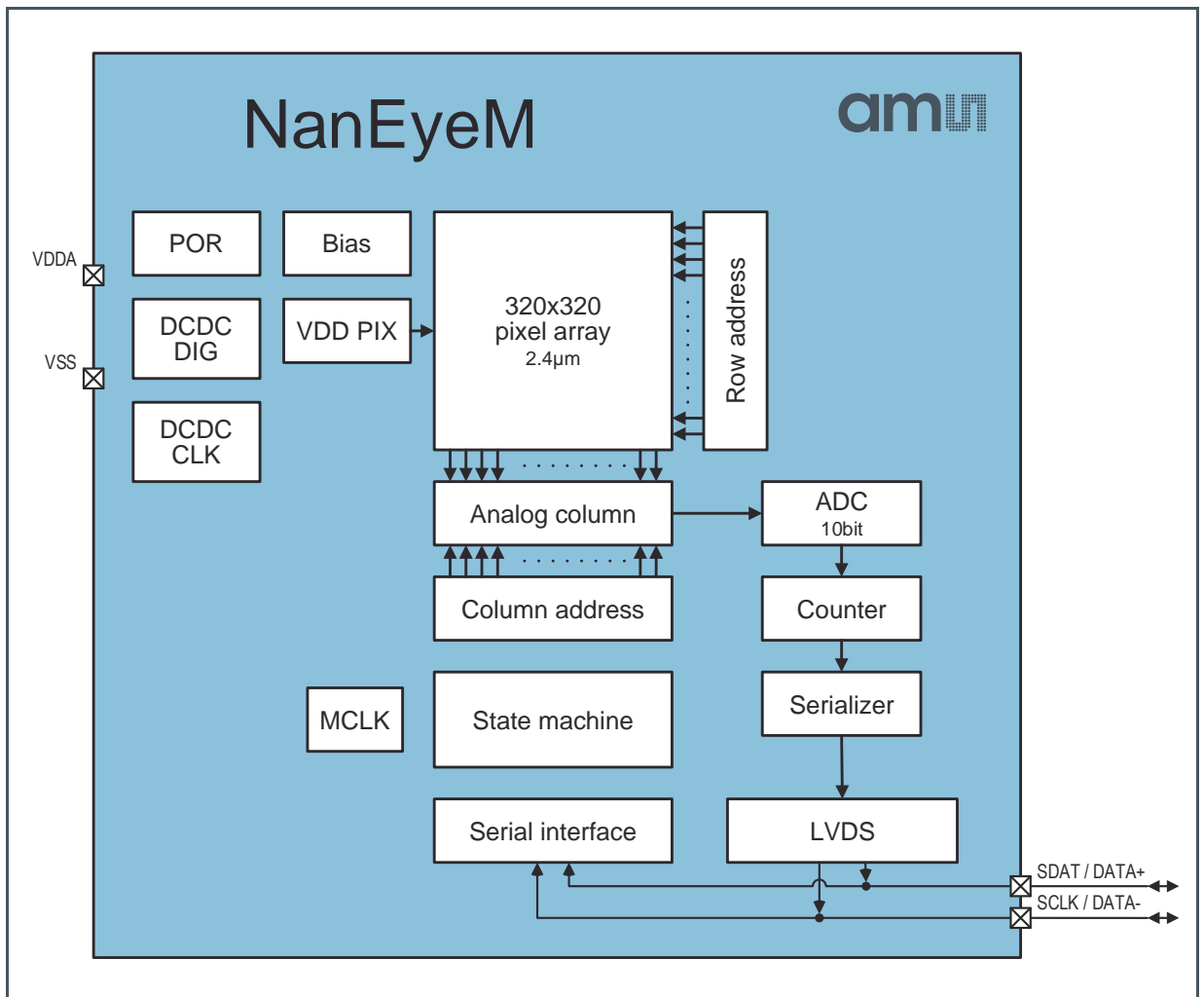
2 Ordering Information

Ordering Code	Package	Optics	Delivery Form	Delivery Quantity
RGB version				
NEM_RGB_2M_FOV120_F4.0	with 2 m cable	FOV120; F4	Spool	n/a
NEM_RGB_2M_FOV120_F4.0_FF[1]	with 2 m cable	FOV120; F4	Spool	n/a
NEM_RGB_2.5M_FOV120_F4.0	with 2.5 m cable	FOV120; F4	Spool	n/a

[1]   Non standard variant, for availability please check with our sales team.

ℹ Information

As module the device is mounted on a flat ribbon cable measuring up to 2 m in length that connects to the base station. However, if the customer requirements are discussed, it may be possible to assemble a slightly longer cable (up to 3 m).

ℹ Information

Device tractability is based on the serial numbers labeled on the spools.

⚠ CAUTION

The module is NOT supplied sterile! Medical use of the system, not integrated into a medical device, may lead to serious harm, illness or death!

3   Pin Assignment

3.1   Pin Diagram

Figure 3:
Pin Assignment Module Cable (camera front view)

	1	2	3	4	5	6
4-wire cable	VSS	SCLK / DATA-	SDAT / DATA+	VDDA		

Figure 4:
4-Wire Cable Pinout
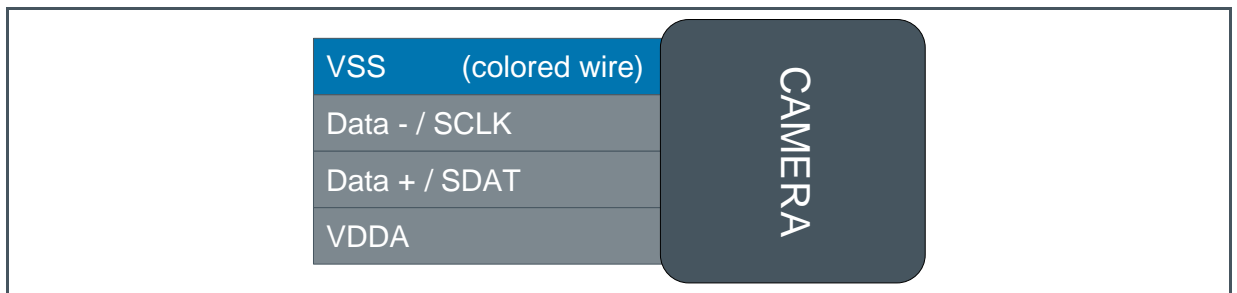
Figure 5:
6-Wire Cable FlexPCB Connector Pinout
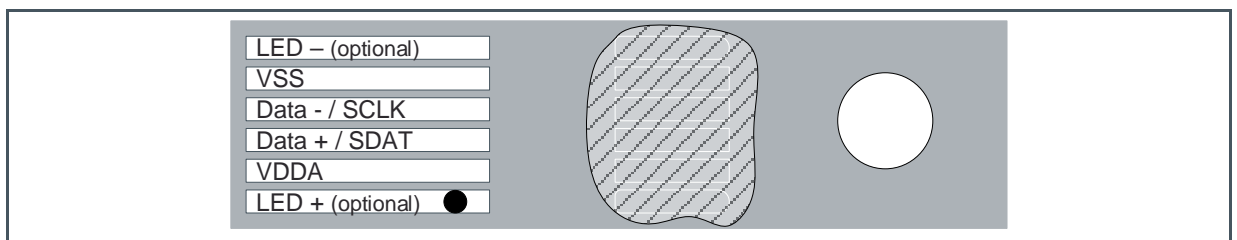
3.2 Pin Description

Figure 6:
Pin Description of NanEyeM

Pin Number		Pin Name	Pin Type[1]	Description
Cable 4-Wire	**Connector 6-Wire**			
	6	LED-	AO	LED cathode
1	5	VSS	VSS	Ground supply
2	4	SCLK / DATA-	DIO	Serial clock input, LVDS neg. output
3	3	SDAT / DATA+	DIO	Serial data input/output, LVDS pos. output
4	2	VDDA	Supply	Positive supply
	1	LED+	AI	LED anode

[1] Explanation of abbreviations:
DIO   Digital Input/Output
AI   Analog Input
AO   Analog Output

4 Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated under "Operating Conditions" is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Figure 7
Absolute Maximum Ratings of NanEyeM

Symbol	Parameter	Min	Max	Unit	Comments
Electrical Parameters					
V_{DDA}	Supply Voltage to Ground	-0.5	3.6	V	
V_{SCLK}, V_{SDAT}	Input Pin Voltage to Ground	-0.5	3.6	V	
Electrostatic Discharge					
ESD_{HBM}	Electrostatic Discharge HBM		± 2	kV	JEDEC JS-001-2017
Temperature Ranges and Storage Conditions					
T_A	Operating Ambient Temperature Full Module	15	55[1]	°C	Full module incl. cable
	Silicon Sensor only	0	70[1]	°C	Good image quality 15 to 55 °C only
RH_{NC}	Relative Humidity (non-condensing)	5	85[1]	%	
T_{STRG}	Storage Temperature Range	- 40	30	°C	[2]
RH_{NC_STRG}	Long Term Storage Humidity	0	60	%	
t_{STRG}	Storage Time		3	yrs	
$MSL_{M+CABLE}$	Moisture Sensitivity Level Lens Module with Cable		N/A		Not applicable as only the cable gets soldered not the module

(1)   Long term exposure toward the maximum operating temperature will accelerate device degradation.
(2)   UV curing process is in our conviction not causing any harm to the sensor.

5 Electrical Characteristics

The parameters with Min and Max values are guaranteed with production tests or SQC (Statistical Quality Control) methods. Parameters without tolerance are typical values.

Figure 8:
Electrical Characteristics of NanEyeM

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
VDDA	Supply Voltage		3.2	3.3	3.4	V
$VN_{RMS}VDDA$	RMS noise on VDDA				5	mV
$VN_{PP}VDDA$	Peak to peak noise on VDDA				20	mV
P_{CLK_STD}[1]	Internal pixel clock	set by mclk_mode [1:0] and high_speed[0]		1.03 2.05 4.09		MHz
P_{CLK_HS}[2]	Internal pixel clock high speed	set by mclk_mode [1:0] and high_speed[0]		1.31 2.59 5.22		MHz
$P_{tot\_3.3}$	Total power consumption	Idle mode = OFF, MCLK=31 MHz		12		mW
		Idle mode = ON		3.2		mW
Digital Upstream Interface						
V_{IL}	SCLK,SDAT Low Level input voltage		-0.3		0.4	V
V_{IH}	SCLK,SDAT High Level input voltage		VDDA -0.3		VDDA +0.3	V
T_S	Setup time for upstream configuration relative to SCLK		3			ns
T_H	Hold time for upstream configuration relative to SCLK		3			ns
f_{SCLK_LVDS}	SCLK frequency in LVDS				2.5	MHz

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
LVDS Downstream Interface						
V_{CM}	Common mode output voltage (DATA+/-)		1	1.4	1.8	V
$I_{DATA+,DATA-}$	LVDS output signal current,	Set by output_curr[1:0]		600 … 2000		µA
B_{CLK_STD}	Bit clock for serial data transmission (12x Pclk)	Set by mclk_mode[1:0] and high_speed[0]		12 25 49		MHz
B_{CLK_HS}	Bit clock for serial data transmission high speed (12x Pclk)	set by mclk_mode[1:0] and high_speed[0]		16 31 63		MHz
J_{DATA}	Jitter data clock		-20		20	%
	LVDS differential peak-peak swing	Zterm=120Ω		72…240		mV
$T_{slew, rising}$	Output slew rate of rising edge			3		ns
$T_{slew, falling}$	Output slew rate of falling edge			3		ns

(1)   _STD –> assuming High Speed bit OFF
(2)   _HS -> assuming HS Speed bit ON

Figure 9:
Electro-Optical Characteristics of NanEyeM

Parameter	Value	Remark
Resolution	102.4 kP, 320 (H) x 320 (V)	
Pixel size	2.4 µm x 2.4 µm	
Optical format	1/15"	
Pixel type	4T shared, FSI	
Shutter type	Rolling Shutter	
Color filters	RGB (Bayer Pattern)	
Micro lenses	Yes	
Lens stack	BF = 8 mm DOF = 4 mm to infinite EFL = 367 µm	Triple element lens
Programmable register	Sensor parameter	Exposure time, dark level, frame rate, analog gain and LVDS drive current
Programmable gain	4 steps 0.8x/1x/1.3x/2x	Analog
Exposure times	0.13 – 261 ms	@ default main clock
ADC	10-bit	Column ADC
Frame rate	4 - 38 fps (5 - 49 fps HS mode)	Adjustable via register settings
Output interface	1x LVDS @ 63 Mbit/s	@ 49 Hz
Size	1050 µm x 1050 µm ±60 µm	Module including sensor, lens stack, side wall painting and cable assembly

Figure 10:
Electro-Optical Parameter

Parameter	RGB	Unit
Responsivity	8.9	DN/nJ/cm^2
Full well capacity	6.2	ke-
Conversion gain	0.137	DN/e-
QE	42.5	%
Temporal read noise in dark / dark noise	0.84 6.1	DN e-
Dynamic range	60	dB
SNR (50% sat)	34	dB
SNR max	38.4	dB
Dark current @ 60 °C	9.2	DN/s
DSNU	0.84	DN
PRNU	1.3	%
FSD	860	DN

(1)   Measured on a RGB sensor at 530 nm illumination, for MCLK=25 MHz setting. The values are all without software correction. The measurement methods used to get these values are those recommended by the European Machine Vision Association standard 1288 for the Machine Vision Sensors and Cameras: http://www.emva.org/standards-technology/emva-1288/

(2)   The values show in the table are averaged values across several samples and different operating points (supply, clock speed, gain, etc).

6 Typical Operating Characteristics
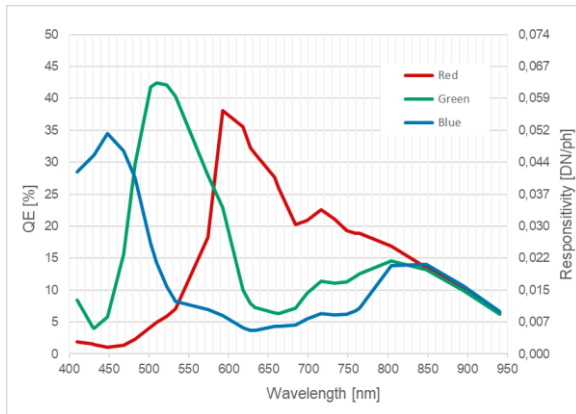
Figure 11:
QE & Responsibility (RGB)
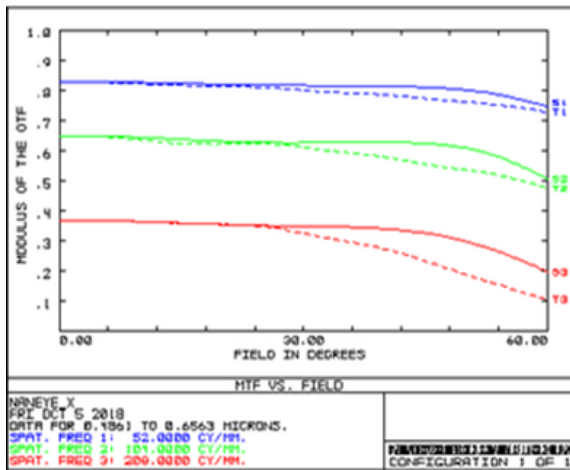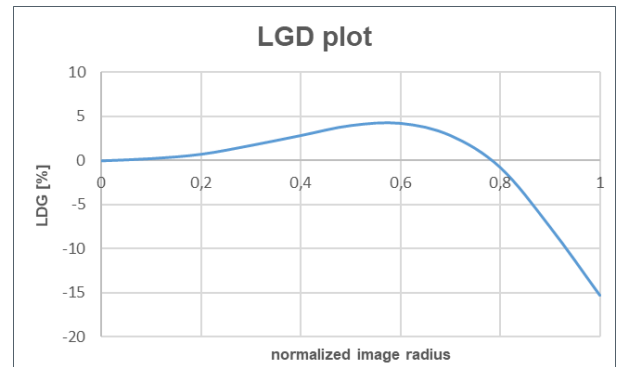

Figure 12:
MTF

Figure 13:
Distortion

7 Functional Description

7.1 Sensor Architecture

Figure 2 shows the image sensor architecture. The internal state machine generates the necessary signals for image acquisition. The image information received in the pixels (rolling shutter) is read out sequentially, row-by-row. On the pixel output, an analog gain is possible. The pixel values then passes to a column ADC cell, in which analog to digital conversion is performed. The digital signals are then read out over a LVDS or single ended output channel.

7.1.1 Pixel Array

The pixel array consists of 320 x 320 square rolling shutter pixels with a pitch of 2.4 μm (2.4 μm x 2.4 μm). The pixel architecture used in this sensor is a 4T type structure, with two pixel vertically shared. This results in an optical area of 768 μm x 768 μm (1.09 mm diameter).

Figure 14:
Pixel Array
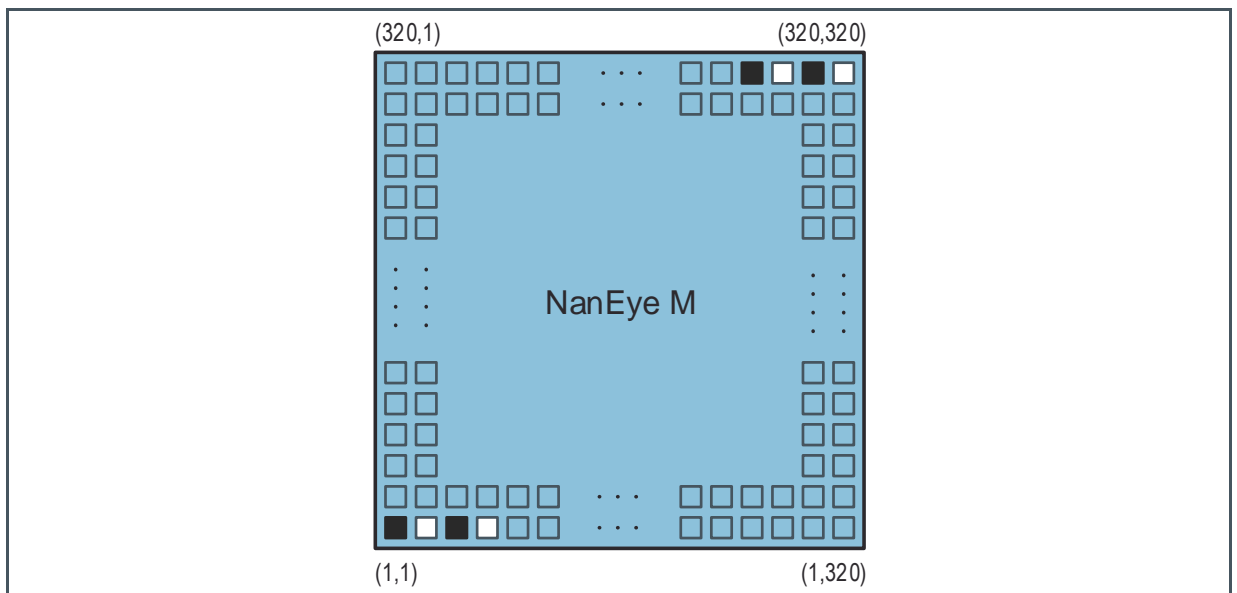
The pixels are designed to achieve maximum sensitivity with low noise (using CDS). Micro lenses are placed on top of the pixels for improved fill factor and quantum efficiency.

There are two electrical black pixels and two electrically saturated pixels on the upper right and lower left hand corner, which may be used to check consistency of received data.

Black pixel (1,1) can be used to compensate the black offset by subtraction it from the individual received pixel values.

7.1.2 Analog Front End

The analog front end consists of 2 major parts, a column amplifier block and a column ADC block.

The column amplifier prepares the pixel signal for the column ADC. The column ADC converts the analog pixel value into a digital value. The architecture allows a full linear AD conversion of 10 bits, with a programmable conversion gain. All gain and offset settings can be programmed using the Single Ended Serial interface.

7.1.3 LVDS Block

The LVDS block converts the digital data coming from the column ADC into standard serial LVDS data. During transfer of the image data, the pixel values are transmitted in bit serial manner with 12 bits and embedded clock using Manchester coding [start bit (1 bit) + data (10 bit) + stop bit (1 bit)]. The sensor has one LVDS output pair.

7.1.4 State Machine

The state machine will generate all required control signals to operate the sensor. The clock is derived from an on-chip master clock generator (LVDS mode). The clock speed and so the number of transmitted frames can be set via registers bits. A detailed description of the registers and sensor programming can be found in chapter 7.4.2 and chapter 8 of this document.

7.1.5 Single Ended Serial Interface

The single ended serial interface is used to load the registers with data. It is multiplexed with the LVDS interface, data can be send in the frame windows of the receiving image information. The data in these registers is used by the state machine and ADC block while driving and reading out the image sensor. Features like exposure time, gain, offset and frame rate can be programmed using this interface. Chapter 7.4.2 and chapter 8 contain more details on register programming.

The sensor will start up in IDLE MODE, having the single ended serial interface active until the idle mode is deactivated.

7.1.6 Optics

The optional optics available for the sensor is a high performance miniature lens module. It will be directly mounted on the image sensor and has its best focus position defined by design, so no mechanical set of focus is needed. The front of the lens module is made of D 263®T eco clear borosilicate glass. The design is made in such way that the surface towards the object is flat, so the

lens performance is not influenced by the medium between the object and lens. Only the opening angle of the lens is reduced when the system operates in water.

7.2 Driving the NanEyeM

The NanEyeM image sensor is based on CMOS technology and is a system on chip, which means that all needed clocks and additional supplies are generated on-chip.

7.2.1 Supply Voltage

The sensor operates from a single supply voltage VDDA. In addition, a VDDPIX (reset voltage for the pixels) as well as separated supplies for digital blocks are generated internally.

For reference schematic and external components please refer to chapter 9 Application Information.

7.2.2 Start-Up Sequence

The sensor is fully self timed and operates in a free running master mode. After power up, the sensor performs an internal power on reset, and then moves to IDLE MODE, having the single ended serial upstream interface active. This gives the possibility to adjust the sensor settings, especially selecting the output mode, before disabling the idle mode and starting the image data transmission.

7.2.3 Reset Sequence

No special reset sequence needed.

7.2.4 Frame Rate

The frame rate can be adjusted be changing the settings for the master clock (MCLK). There is also a high speed mode available to generate even higher frame rates.

7.3 Matrix Readout

To guarantee a high fill factor a pixel layout with the two vertical electrical shared pixels has been developed.

The matrix readout is according the following sequence:

● Read first row (R1.1), starting in the position (1;1) and finishing in the position(1;320)
● Read second row (R1.2), starting in the position (2;1) and finishing in the position (2;320)
...
● Read last row (R160.2), starting in the position (320;1) and finishing in the position (320;320)

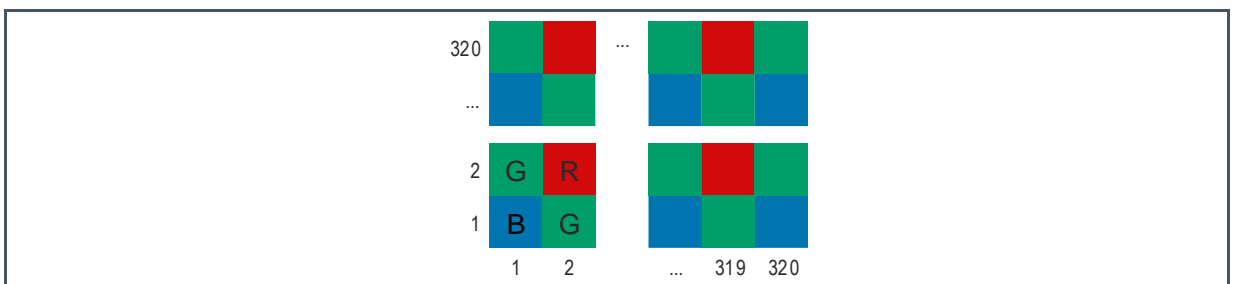Note that (row,column), i.e., (2;1) represents row 2 column 1.

Figure 15:
Shared Pixel Matrix Readout
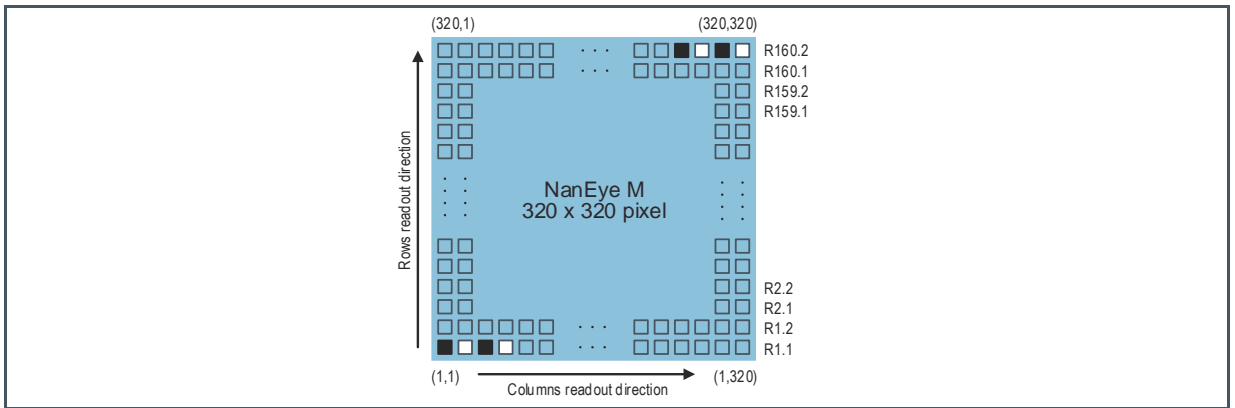
7.3.1 Color Filters

The color filters used for NanEyeM are applied in a Bayer pattern. The first pixel read-out, pixel (1,1), is the bottom left one and has a blue filter.

Figure 16:
**Colored Version Bayer Pattern Matrix**

7.3.2 Sequence of Operation

The NanEyeM sensor will start in INTERFACE MODE waiting for configuration and request to leave idle mode. After the request, the sensor will go to a loop of 4 modes, which are described below. The frame time is defined by the total duration of these 4 modes:

- INTERFACE MODE: during this mode, which is active during 648 PP (Pixel Period) it is possible to write and update the register configuration. In this mode DATA pins are used as SDAT and SCLK.
- SYNC MODE: during this mode the sensor is transmitting training pattern to allow the sensor synchronization (duration of 656 PP).
- DELAY MODE: during this mode the sensor will keep the previous state during the programmed time while sending the sync pattern. The time can be programmed between 2 to 498 row periods.
- READOUT MODE: during this mode the sensor assumes that the synchronization is done and starts to send image data, the pixel values are transmitted in bit serial manner over an LVDS channel with embedded clock, or single ended depending on the selected transmission mode. Note that before each row a Start of Row identification is sent with the duration of 8 PP and that after the last row an End Of Frame is sent with the duration of 8 PP.

The sensor transmit synchronization pattern at least for the period of four rows, corresponding to the SYNC MODE and to the DELAY MODE (if set to the minimum programmable value). But it can transmit the pattern continuously for a longer time period, according the rows_delay[4:0] value programmed, which can take from 2 to 498 row clock period (2*328PP to 498*328PP).

Figure 17:
Sequence of Operation
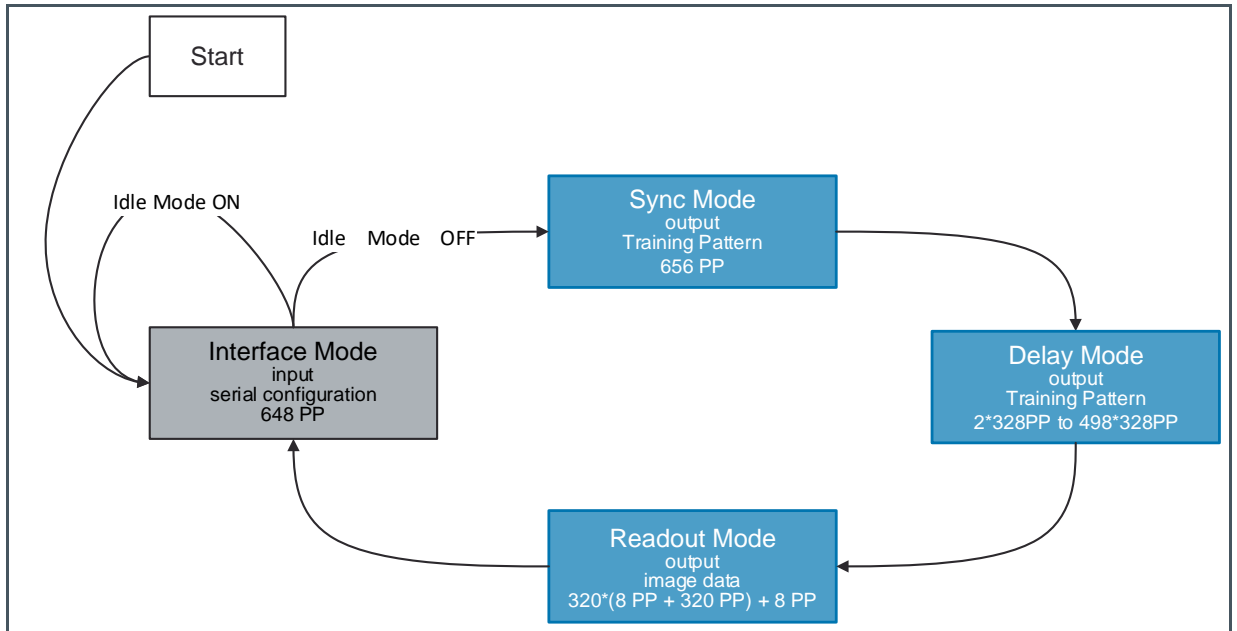
(1)   PP refer to Pixel Period.

Figure 18:
Matrix Readout Sequence

Phase #	Status	Start bit	Data XOR	Interface Status	Duration	Function
INTERFACE MODE						
SERIAL	Time for serial configuration[1]	N/A	N/A	S_INT IN	648 PP[2]	Serial Interface
SYNC MODE						
SYNC	Transmission of continuous 0	0	Yes	LVDS OUT	328*2 PP	Re-Synchronization
DELAY MODE						
DELAY	Transmission of continuous 0	0	Yes	LVDS OUT	328*2 PP to 328*498 PP	Programmed Delay
READOUT MODE						
RD R1.1	Transmission of continuous 0	0	Yes	LVDS OUT	8 PP	Start of Row
	Transmission of 320 pixel values	1	Yes	LVDS OUT	320 PP	Image Data (Row 1)
RD R1.2	Transmission of continuous 0	0	Yes	LVDS OUT	8 PP	Start of Row
	Transmission of 320 pixel values	1	Yes	LVDS OUT	320 PP	Image Data (Row 2)
RD R2.1	Transmission of continuous 0	0	Yes	LVDS OUT	8 PP	Start of Row
	Transmission of 320 pixel values	1	Yes	LVDS OUT	320 PP	Image Data (Row 3)
RD R2.2	Transmission of continuous 0	0	Yes	LVDS OUT	8 PP	Start of Row
	Transmission of 320 pixel values	1	Yes	LVDS OUT	320 PP	Image Data (Row 4)
Readout other rows						
RD R160.1	Transmission of continuous 0	0	Yes	LVDS OUT	8 PP	Start of Row
	Transmission of 320 pixel values	1	Yes	LVDS OUT	320 PP	Image Data (Row 319)
RD R160.2	Transmission of continuous 0	0	Yes	LVDS OUT	8 PP	Start of Row
	Transmission of 320 pixel values	1	Yes	LVDS OUT	320 PP	Image Data (Row 320)
RD EOF	Transmission of continuous 0	0	No	LVDS OUT	8 PP	End of Frame

(1)   It is recommended to drive the data bus during the entire upstream communication phase, even if no register data is sent to the sensor. This is to avoid pick up of EMI on the lines floating during the communication phase when not driven by the application.

(2)   When IDLE MODE is OFF. If IDLE MODE is enabled the sensor remains in this working mode until the IDLE MODE is disabled.

⚠️ **CAUTION**

- The sensor fully is self timed and cycles between the downstream and the upstream mode. Therefore it is the user's responsibility to tristate the upstream drivers of the serial configuration link prior to the start of data transmission from the sensor.

- Due to the limited current output from the sensor it is not expected that conflicting drive of the data lines will permanently destroy the sensor, however this condition would seriously degrade the data integrity and is not qualified in terms of device reliability and life time.
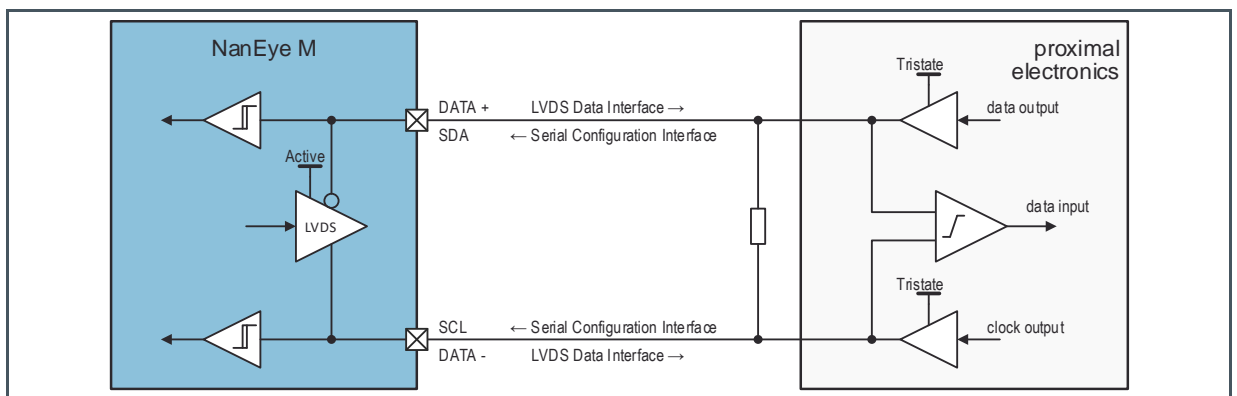
7.4   Serial Interface

The chip features a bi-directional data interface. During transfer of the image data, the pixel values are transmitted in bit serial manner over an LVDS channel with an embedded clock. After each frame, the data interface is switched for a defined time to an upstream configuration interface. This needs a synchronization every time it passes from the upstream to a new downstream mode at the image receiver side. The positive LVDS channel holds the serial configuration data and the negative channel holds the serial interface clock.

By register configuration the downstream interface can be chosen to be LVDS type with the serial data EXOR combined with the bit clock (Manchester Code).

For any application where the sensor is used with connection cable between the sensor and the receiver, the use of the LVDS mode is recommended.
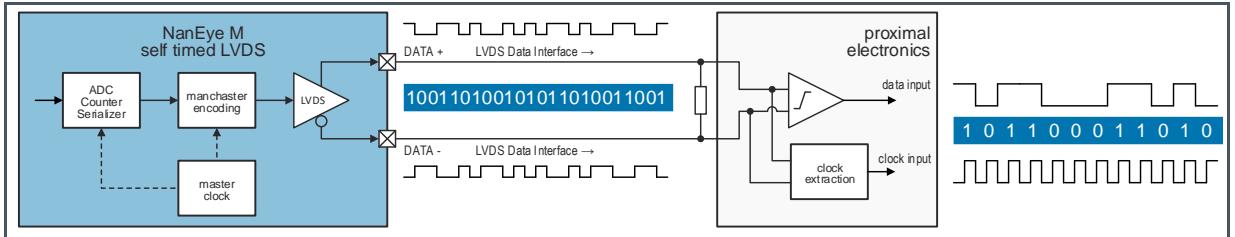
Figure 19:
Data Interface Between Sensor and Proximal Electronics

7.4.1 NanEyeM LVDS Data Interface (Downstream)

The NanEyeM image data on chip is generated as a 10-bit representation. A start and a stop bit is then added to the data. The bit serial data interface then transmits the data with 12 times the pixel frequency.

Figure 20:
LVDS Downstream Mode

Data Word

The data word is EXOR gated with the serial clock before sent bit serial according to the following scheme:

Figure 21:
Data Word Encoding

Bit #	0	1	2	3	4	5	6	7	8	9	10	11
Function	Start	Pixel Data (10 bits)										Stop
Content	1	MSB									LSB	0

An example of this is:

- 10-bit data word: 0110001101
- Including start and stop bits: **1**0110001101**0**
- 12-bit word EXOR with the data clock:

    - 01 01 01 01 01 01 01 01 01 01 01 01 - data clock (main clock)
    - 11 00 11 11 00 00 00 11 11 00 11 00 – 12-bit data @ data clock frequency
    - 10 01 10 10 01 01 01 10 10 01 10 01 - data word result

Training Pattern Word

The training pattern is transmitted during SYNC MODE and DELAY MODE, and also during READOUT MODE as Start of Row identification. It is a 12-bit word with all 0's, start and stop bit also at 0, EXOR gated with the main clock.

Figure 22:
Training Pattern Word Encoding

| Bit #	0	1	2	3	4	5	6	7	8	9	10	11
Function	Start	Start Row										Stop
Content	**0**	0	0	0	0	0	0	0	0	0	0	0

An example of this is:

- 10-bit data word: 0000000000
- Including start and stop bits: **0**00000000000**0**
- 12-bit word EXOR with the data clock:

    - 01 01 01 01 01 01 01 01 01 01 01 01 - data clock (main clock)
    - 00 00 00 00 00 00 00 00 00 00 00 00 – 12-bit at 0's @ data clock frequency
    - 01 01 01 01 01 01 01 01 01 01 01 01 – training pattern word result

End of Frame Word

The end of frame word is similar to the training pattern, it is a 12-bit word with all 0's, start and stop bit also at 0, but in this particular case it is not EXOR with main clock. It is transmitted in the end of the readout phase (READOUT MODE).

Figure 23:
End of Frame Word Encoding[1]

Bit #	0	1	2	3	4	5	6	7	8	9	10	11
Function	Start	Start Row										Stop
Content	**0**	0	0	0	0	0	0	0	0	0	0	0

(1)   No EXOR with main clock!

An example of this is:

- 10-bit data word: 0000000000
- Including start and stop bits: **0**00000000000**0**
- 12-bit word **no** EXOR with the data clock:

    - 01 01 01 01 01 01 01 01 01 01 01 01 – data clock (main clock)
    - 00 00 00 00 00 00 00 00 00 00 00 00 – 12-bit at 0's @ data clock frequency
    - 00 00 00 00 00 00 00 00 00 00 00 00 – end of frame word result

Start of Row Identification

Note that the start of row identification consist in sending the training pattern (010101010101010101010101) 8 times.

After 8 times transmitting the training pattern the data transmission for a particular row starts. Note that is possible to identify a new row easily by detecting two ones after the eight training pattern words. The ones appearance results from the last bit of the start line and the first bit of the image data (start bit XOR with data clock) as is shown below:

Figure 24:
Start of Row Identification

'01010101010101010101010101' ⟩ 6x training pattern ⟩ '010101010101010101010101' **'10011010010101101001011001'**

Start of new row
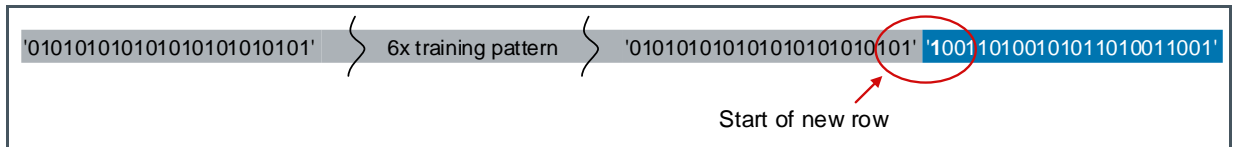
End of Frame Identification

The End of Frame identification is sent after the last row and before the Serial Phase, it is the End of Frame word repeated 8 times.

Figure 25:
End of Frame Identification

'00 00 00 00 00 00 00 00 00 00 00 00' ⟩ 6x end of frame ⟩ '00 00 00 00 00 00 00 00 00 00 00 00'
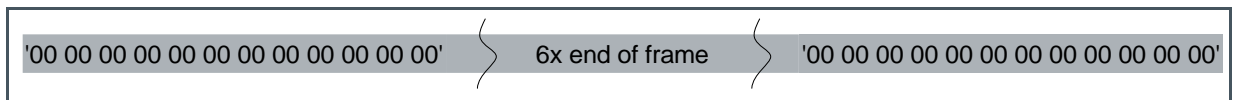
Re-Sync Identification

The Re-sync identification is sent during the SYNC MODE after the INTERFACE MODE (serial upstream configuration phase) in order to restart the sensor synchronism. It will send the training pattern word during 656 PP.

DELAY MODE Identification

During DELAY MODE the training word is sent 2*328 to 498*328 times. The number of repetitions can be programmed with rows_delay[4:0].

7.4.2 Serial Configuration Interface (Upstream)

The serial interface is active for 648 PP (INERFACE MODE) and consists of two 16-bit write only registers. The registers can be updated between frames by the serial data line - SDAT and by the serial clock line – SCLK external controlled signal. The registers are written by sending a 4-bit update code, followed by a 3-bit register address (only register 000 and 001 are implemented), 16-bit register data and a bit fixed to "0".

Sending data to the sensor must not be done with the first clock pulse provided to the sensor. It is required to send at least one activation clock pulse upfront. It needs to be avoided to send configuration data in the last PP of the INTERFACE MODE.

All data is written MSB to LSB. Data is captured on the rising edge of SCLK. It is recommended to change SDAT on the falling edge of SCLK to guarantee maximum set-up and hold times.

The content of the input shift register is updated to the effective register, once a correct update code (1001) has been received and shifted by 24 serial clocks. The input shift register is reset to all 0's, 1 SCLK clock after the code detection.

The below table indicates the sequence of writing update code, register address and register data.

Figure 26:
Register Update Sequence

# Rising Edge of SCL after Reset	1	2	3	4	5	6	7	8	9	…	22	23	24
Function		Update Code				Register Address[1]			Register Content (16-bit)				Reset
Content	1	0	0	1	**0**	**0**	**X**	MSB				LSB	0

[1] Register address 000 for Configuration_0 register
Register address 001 for Configuration_1 register

A correct sequence must have 24 SCLK, where:

● The first 4 SCLK are for detection of a correct code (must be 1001).
● The next 3 SCLK will indicate the register to be written (000 or 001).
● The next 16 SCLK will pass the data information (from MSB to LSB).
● Finally the last SCLK will pass the bit "0" that is used to separate words.

To signalize the end of the INTERFACE MODE, the device transmit a specific word in the last PP:

● LVDS : 00 00 00 00 00 00 00 01 01 01 01 01

7.5 Sensor Programming

This section explains how the NanEyeM can be programmed using the on-board registers.

7.5.1 Exposure Time Control

Exposure time is defined based on the amount of rows in reset set by user and the frame rate, which is dependent on the main clock frequency and the delay mode setting. The NanEyeM sensor features a rolling shutter, which means one row is selected for readout while a defined number of previous rows are in reset, and all the others rows are in integration.

Configuring the DELAY MODE at the beginning of each frame, can be used to increase the integration time.

Figure 27:
Row Readout Operation
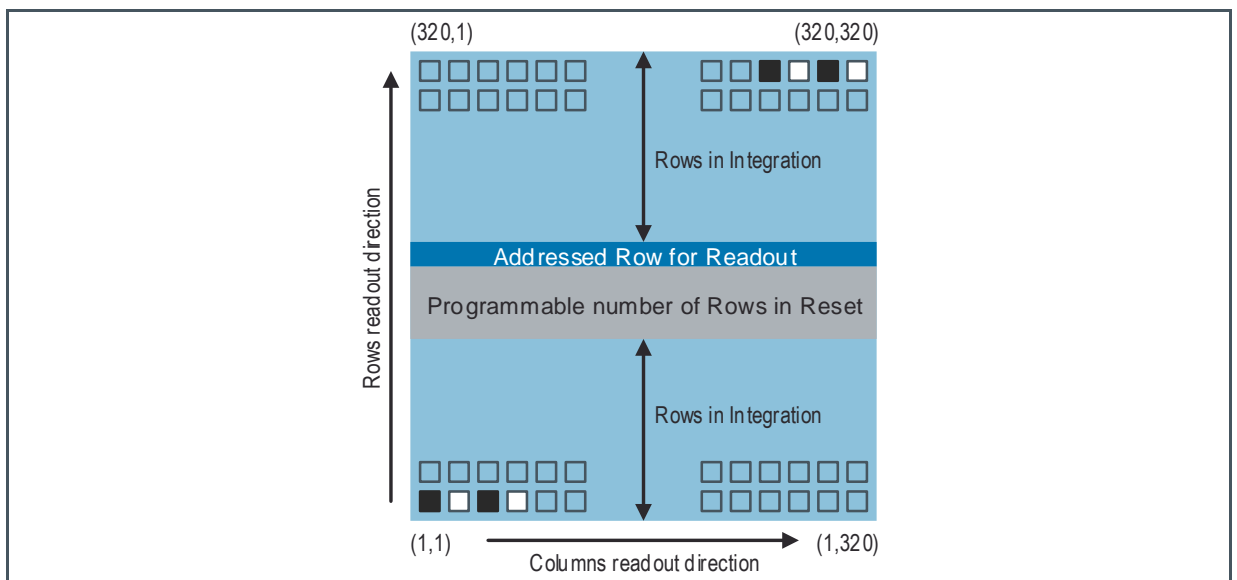
The frame time is defined by a full cycle in the state-machine including the matrix readout as well as the time between frames for INTERFACE, SYNC and DELAY MODE.

Equation 1: Frame Time

$$t_{frame} = t_{rows\_btw\_frame} + t_{rows\_matrix}$$

The effective exposure time thus is given by the formula:

Equation 2: Exposure Time

$$t_{exp} = t_{rows\_btw\_frame} + t_{rows\_matrix} - t_{rows\_in\_reset} - t_{rows\_in\_readout}$$

t_{exp}	= The effective exposure time
$t_{rows\_btw\_frames}$	= Time for of rows between frames
t_{rows_matrix}	= Time for active pixel matrix readout
$t_{rows\_in\_reset}$	= Time of rows in reset
$t_{rows\_in\_readout}$	= Time of rows in readout

Equation 3: Time for Rows between Frame

$$t_{rows\_btw\_frame} = t_{rows\_spi} + t_{rows\_sync} + t_{rows\_delay}$$

$$t_{rows\_spi} = 648\ PP$$
$$t_{rows\_sync} = 2 * 328\ PP = 656\ PP$$
$$t_{rows\_delay} = (16 * rows\_delay[4:0] + 2) * 328\ PP$$

Equation 4: Time for Active Pixel Matrix Readout

$$t_{rows\_matrix} = 320 * 328\ PP + 8\ PP = 104968\ PP$$

Determined by the size of the pixel matrix with 328 PP per each row.
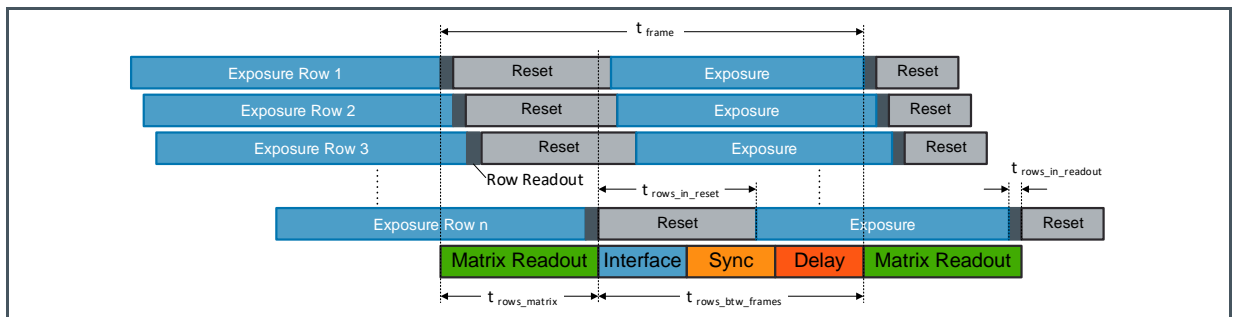
Equation 5: Time for Rows in Reset

$$t_{rows\_in\_reset} = (2 * rows\_in\_reset[7:0] + 2) * 328\ PP$$

rows_in_reset[7:0] maximum value is equal to the total number of sensor rows.

Equation 6: Time for Row in Readout

$$Trow_{in\_readout} = 2 * 328\ PP = 656\ PP$$

Figure 28:
**Row Readout Timing Diagram**

7.5.2   Offset and Analog Gain

It is a 10-bit full linear ADC. The architecture of the ADC allows programming several parameter:

- Voltage Reference for signal (vref[1:0])
- Ramp Gain (ramp_gain[1:0])
- Ramp Offset Voltage (offset_ramp[1:0])
- CDS gain (cds_gain[0])
- CDS current (bias_curr_increase[0])

See the configurable values in 8 Register Description.

Figure 29 :
ADC Settings
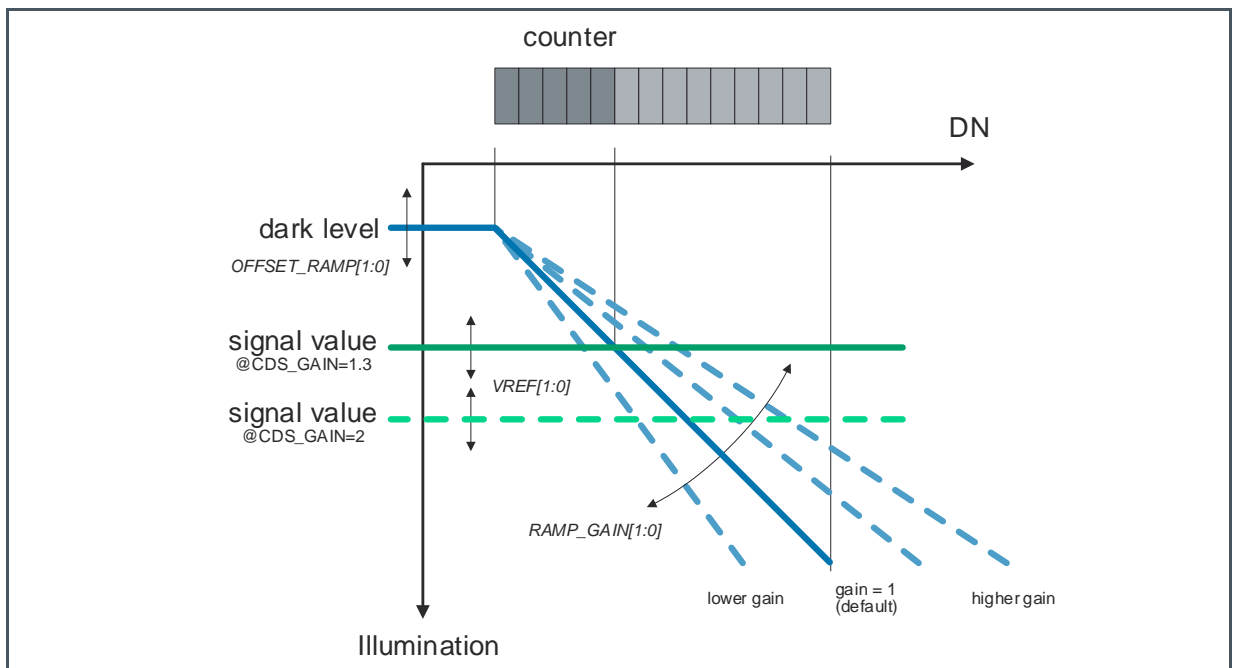
8 Register Description

8.1 Detailed Register Description

Figure 30:
Configuration_0 Register

Addr: 00h		Configuration_0		
Bit	**Bit Name**	**Default**	**Access**	**Bit Description**
15:8	rows_in_reset[7:0]	80h	WO	Sets the number of rows in reset: $rows_{in\_rst} = 2*rows\_in\_reset[7:0]+2$ **Default: 258**
7:6	vrst_pix[1:0]	10b	WO	Sets the pixel reset voltage: 0: 2.2 V 1: 2.4 V **2: 2.6 V** (recommended) 3: 3.3 V
5:4	ramp_gain[1:0]	01b	WO	Sets the analog ADC ramp gain: See Figure 31.
3:2	offset_ramp[1:0]	01b	WO	Sets the ramp offset (dark level) value 0: 1.9 V **1: 2 V** 2: 2.1 V 3: 2.2 V (recommended)
1:0	output_curr[7:0]	01b	WO	Sets the LVDS output current 0: 600 µA / 3.9 mA **1: 1200 µA / 5.8 mA** 2: 1800 µA / 7.7 mA 3: 2000 µA / 9.6 mA

Figure 31:
ADC Ramp Gain Settings

MCLK [MHz]	ramp_gain[1:0]	Ramp Gain	MCLK [MHz]	ramp_gain[1:0]	Ramp Gain
12	00	0.79	16	00	0.79
	01	0.99		01	0.99
	10	1.32		10	1.32
	11	1.97		11	1.97
25	00	0.80	31	00	0.81
	01	**1.00**		01	1.01
	10	1.33		10	1.35
	11	2.00		11	2.03
49	00	0.83	63	00	0.83
	01	1.03		01	1.04
	10	1.38		10	1.39
	11	2.07		11	2.10

Figure 32:
Configuration_1 Register

Addr: 01h		Configuration_1		
Bit	**Bit Name**	**Default**	**Access**	**Bit Description**
15:11	rows_delay[4:0]	00h	WO	Sets the number of rows period in delay mode $rows_{delay} = 16*rows\_delay[4:0]+2$ **Default: 2**
10	bias_curr_increase[0]	0b	WO	**0: Nominal bias current** 1: ~2x bias current, reduces settling time for high speed applications
9	cds_gain[0]	1b	WO	0: CDS gain 1.3 (recommended) **1: CDS gain 2**
8	output_mode[0]	1b	WO	0: Do not use **1: LVDS**
7:6	mclk_mode[1:0]	01b	WO	Sets main clock frequency: See Figure 33 0: Main clock 2x **1: Default** 2: Main clock /2 3: Main clock /2
5:4	vref[1:0]	01b	WO	Sets the reference voltage for CDS: 0: 1.9 V **1: 2 V** 2: 2.1 V (recommendet) 3: 2.2 V
3:2	cvc_curr[1:0]	10b	WO	Sets the CVC current: See Figure 34. Recommended to set to 01b.
1	idle_mode[0]	1b	WO	Sets the sensor to work in idle mode with lower power consumption 0: Idle mode disabled **1: Idle mode enabled**
0	high_speed[0]	0b	WO	Sets clock to high speed mode: See Figure 33. **0: MCLK high speed mode off** 1: MCLK high speed mode enabled

Figure 33:
Main Clock Configurations & Frame Rates

high_speed[0]	mclk_mode[1:0]	Description	Interface Speed MCLK [MHz]	Frame Rate [fps]
0	00	Main clock 2x	49.1	38
	01	**Default**	**24.7**	**19**
	1x	Main clock /2	12.3	9
1	00	Main clock 2x	62.6	49
	01	Default HS	31.1	24
	1x	Main clock /2	15.7	12

Figure 34:
CVC Current Settings

MCLK [MHz]	CVC_CURR[1:0]	CVC Current [µA]	MCLK [MHz]	CVC_CURR[1:0]	CVC Current [µA]
12	00	0.36	16	00	0.46
	01	0.79		01	1..03
	10	0.98		10	1.29
	11	1.44		11	1.88
25	00	0.69	31	00	0.90
	01	1.58		01	2.05
	10	**1.98**		10	2.59
	11	2.93		11	3.85
49	00	1.54	63	00	1.75
	01	3.18		01	4.14
	10	4.06		10	5.30
	11	6.07		11	7.95

9   Application Information

9.1   Recommended LVDS Receiver Electronics

The direct interface of the LVDS data to an FPGA or DSP differential input is not guaranteed. It is recommended to use a LVDS detections circuit based on a fast comparator, which fixes the LVDS signals common mode.

Figure 35:
NanEye Interface Schematic (for information only)
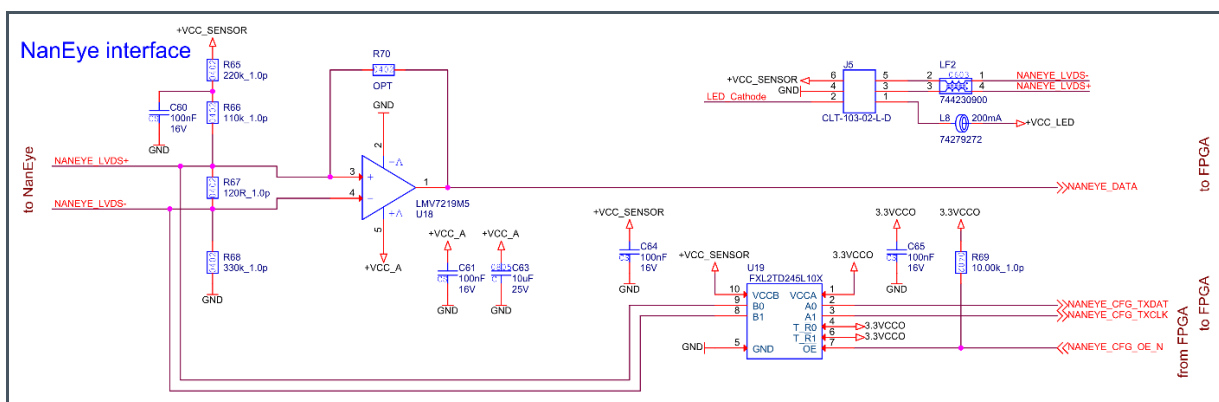
In order to increase the robustness of the de-serialization under the presence of significant jitter, which should be expected from the on chip oscillator, the data is EXOR combined with the data clock.

To reliably de serialize the incoming data, the receiver side should sample the data at least with 750 MHz (> 10x of the MCLK frequency) to properly detect the phase of the transitions.

When defining the drive strength of the up stream drivers in the proximal circuitry it has to be considered that the serial clock and the serial data will couple to each other over the bit lines termination resistor. To reduce noise coupling to the analog electronics the LVDS output current is configured between 600 μA to 2 mA (by serial interface), which will guarantee a save detection and de-serialization based on very low voltage swing LVDS receiver.

Driving the serial configuration data should be carefully designed along with the cables inductance to avoid signal over shoot at the chip side. It is recommended to use slew rate controlled drivers with a low slew rate. No distal termination of the data lines is implemented on chip.

9.2 Supply Generation

Having an LDO to generate a dedicated low noise supply is recommended. It has to be kept in mind that the cable has about 7 Ω per meter length. So for different cable length and clock speeds used it should be verified that the supply voltage at the sensor is within the required range.

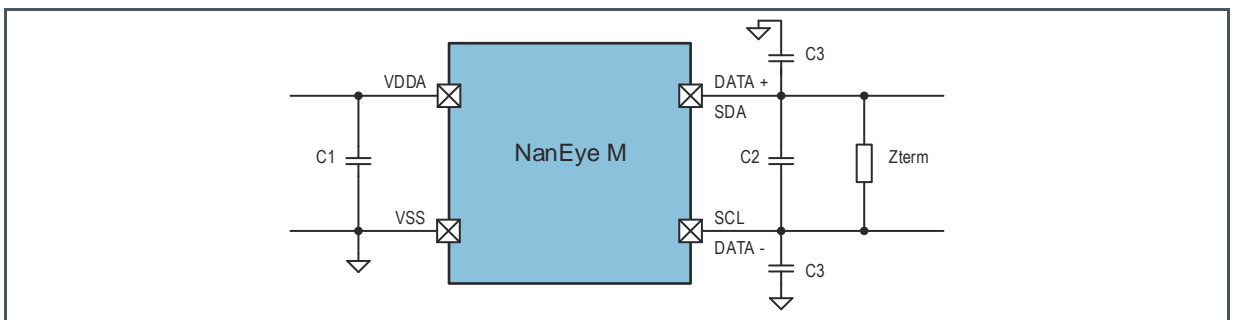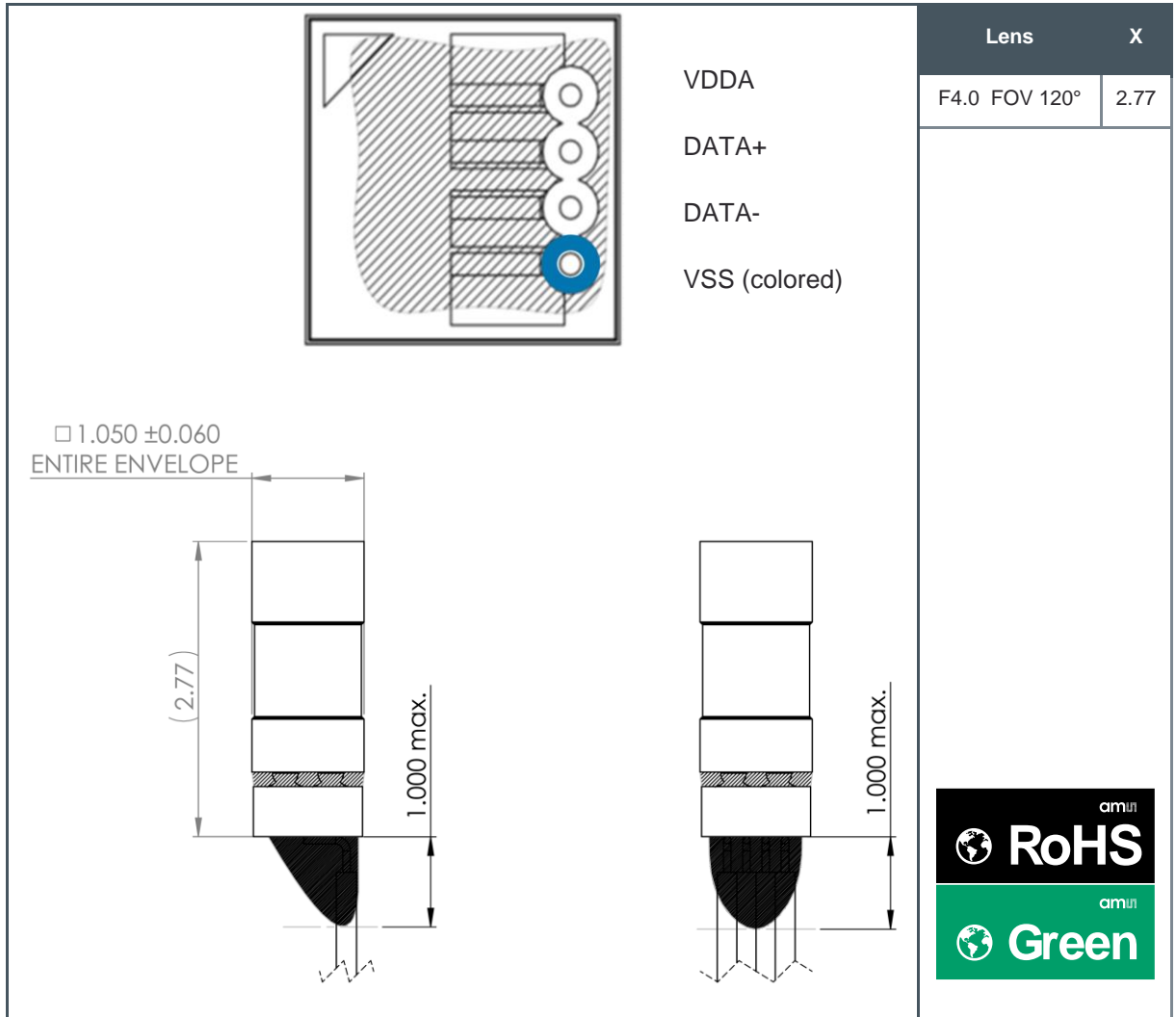## 9.3 External Components

Figure 36:
External Components LVDS

Figure 37:
External Components Recommendations

Component	Description	Nominal Value	Unit
C1	Power supply decoupling	>100	nF
C2	Differential load on LVDS lines (parasitics)	<3	pF
C3	Single ended load on LVDS lines (parasitics)	<5	pF
Zterm	Impedance of LVDS termination	120	Ω

10 Package Drawings & Markings

Figure 38:
NanEyeM with Lens and Cable Soldered (Bended) Package Outline Drawing

Lens	X
F4.0 FOV 120°	2.77

VDDA

DATA+

DATA-

VSS (colored)

☐ 1.050 ±0.060
ENTIRE ENVELOPE

(2.77)

1.000 max.

1.000 max.

(1)   All dimensions are in millimeters. Angles in degrees.
(2)   If not otherwise noted all tolerances are ±0.1 mm.
(3)   This package contains no lead (Pb).
(4)   This drawing is subject to change without notice.

Figure 39:
NanEye FlexPCB Connector
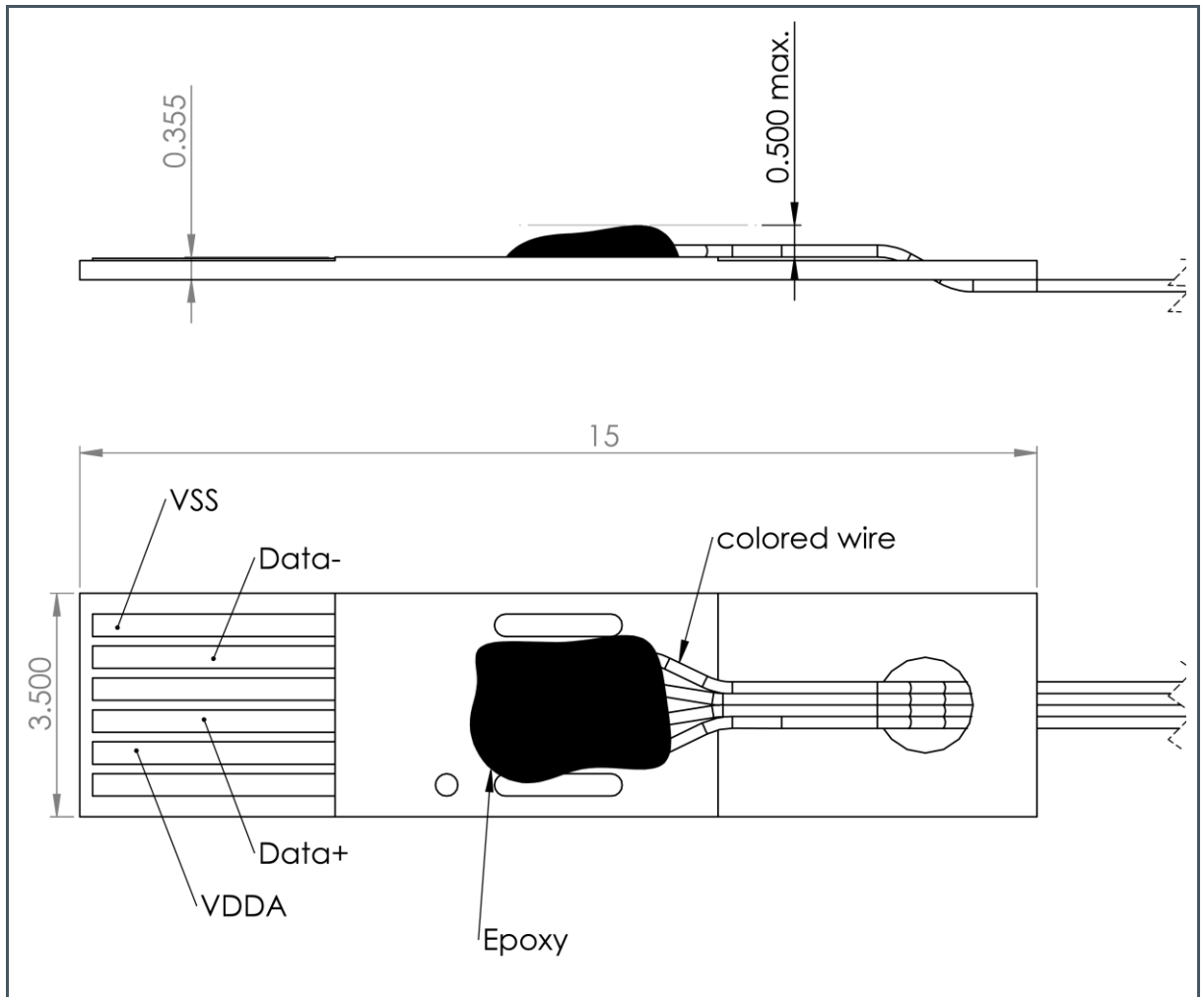
(1)   All dimensions are in millimeters. Angles in degrees.
(2)   If not otherwise noted all tolerances are ±0.1 mm.
(3)   This package contains no lead (Pb).
(4)   This drawing is subject to change without notice.

11 Tape & Reel Information

Figure 40:
Spool Dimensions for Module plus Cable Shipments
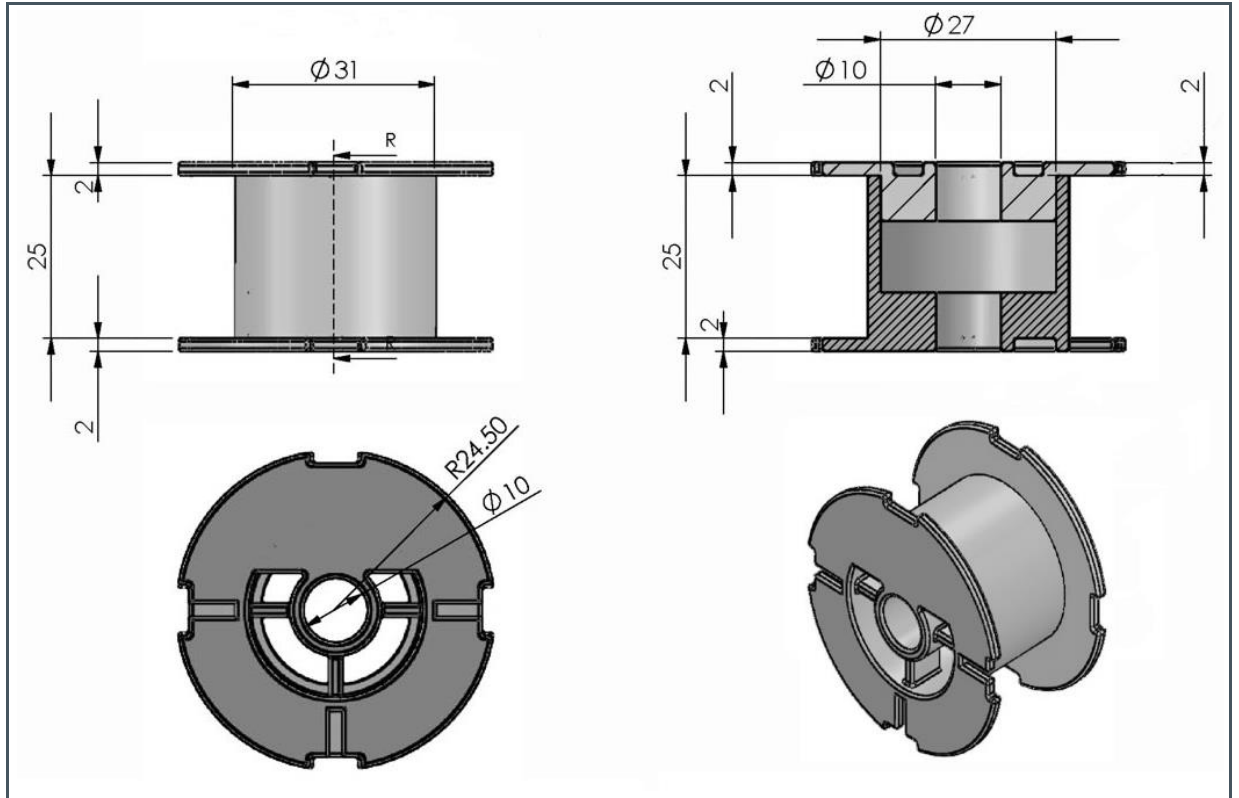
(1)   All dimensions are in millimeters. Angles in degrees.
(2)   If not otherwise noted all tolerances are ±0.1 mm.
(3)   This drawing is subject to change without notice.

12 Appendix

12.1 Evaluation System

Optionally with the NanEyeM module, **ams** provides a base station and software to run the device on a PC in real-time with all necessary image corrections. The complete system consists of the module, the USB interface box and the PC software.

13   Revision Information

Document Status	Product Status	Definition
Product Preview	Pre-Development	Information in this datasheet is based on product ideas in the planning phase of development. All specifications are design goals without any warranty and are subject to change without notice
Preliminary Datasheet	Pre-Production	Information in this datasheet is based on products in the design, validation or qualification phase of development. The performance and parameters shown in this document are preliminary without any warranty and are subject to change without notice
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Changes from previous version to current revision v2-00	Page
Removed CONFIDENTIAL status	all
Changed fps range (including delay option)	3,10
Added new order codes	5
Removed 6-wire cable option	6
Added lens stack parameters	10
Added frame time definition	17, 25
Corrected cable orientation in package drawing	34

● Page and figure numbers for the previous version may differ from page and figure numbers in the current revision.
● Correction of typographical errors is not explicitly mentioned.

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